**Product data sheet** 

## 1. General description

PNP medium power transistors in an ultra thin DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and Side-Wettable Flanks (SWF).

## 2. Features and benefits

- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- Reduced Printed-Circuit Board (PCB) area requirements
- Leadless small SMD plastic package with solderable side pads
- Exposed heatsink for excellent thermal and electrical conductivity
- Suitable for Automatic Optical Inspection (AOI) of solder point

## 3. Applications

- · Linear voltage regulators
- · High-side switches
- · Battery-driven devices
- MOSFET drivers
- Amplifiers

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	1 didilictei	Conditions	141111	1 y P	IVIUA	Oiiit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-80	V
I <sub>C</sub>	collector current		-	-	-1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-2	Α
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; $I_{C}$ = -100 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.01; $T_{amb}$ = 25 °C	100	-	300	



80 V, 1 A PNP medium power transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	Е	emitter		С
3	С	collector	Transparent top view DFN2020D-3 (SOT1061D)	B — E 006aaa231

# 6. Ordering information

## **Table 3. Ordering information**

Type number	Package				
	Name	Description	Version		
BSR33PAS		plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); no leads; 3 terminals; 1.3 mm pitch; 2 mm x 2 mm x 0.65 mm body	<u>SOT1061D</u>		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BSR33PAS	G3

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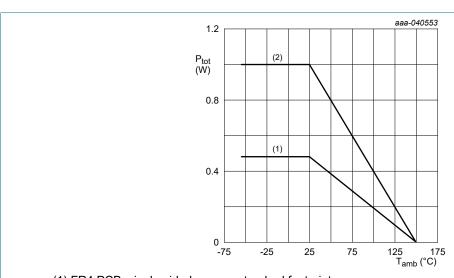
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-90	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-80	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-2	Α
I <sub>BM</sub>	peak base current			-	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.48	W
			[2]	-	1	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, and standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.



- (1) FR4 PCB, single-sided copper, standard footprint
- (2) FR4 PCB, single-sided copper, 1 cm<sup>2</sup>

**Power derating curves** Fig. 1.

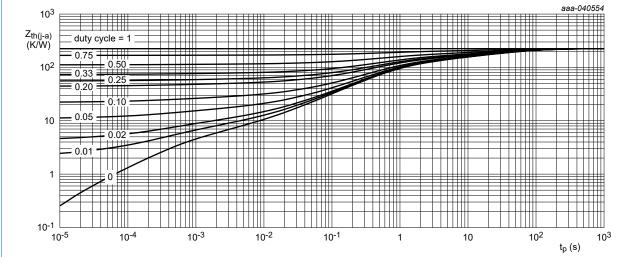
#### 80 V, 1 A PNP medium power transistor

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

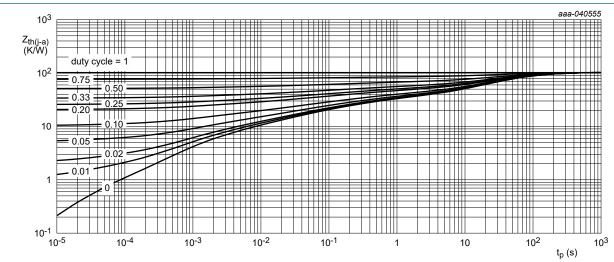
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	-	260	K/W
junction to ambient	junction to ambient		[2]	-	-	125	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	12	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.



FR4 PCB,single-sided, 70 µm copper, standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided, 70 µm copper, mounting pad for collector 1 cm<sup>2</sup>

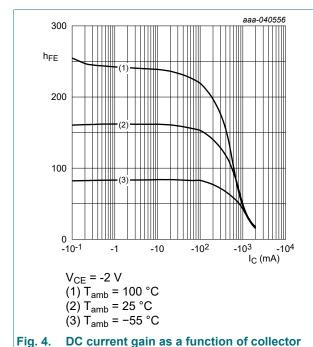
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

#### 80 V, 1 A PNP medium power transistor

## 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -60 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current (emitter open)	V <sub>CB</sub> = -60 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current (collector open)	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; $I_{C}$ = -100 μA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.01; $T_{amb}$ = 25 °C	30	-	-	
		$V_{CE}$ = -5 V; $I_{C}$ = -100 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.01; $T_{amb}$ = 25 °C	100	-	300	
		$V_{CE}$ = -5 V; $I_{C}$ = -500 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.01; $T_{amb}$ = 25 °C	50	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = -150 mA; $I_B$ = -15 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.01; $T_{amb}$ = 25 °C	-	-	-0.25	V
		$I_C$ = -500 mA; $I_B$ = -50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.01; $T_{amb}$ = 25 °C	-	-	-0.5	V
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -150 mA; $I_B$ = -15 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.01; $T_{amb}$ = 25 °C	-	-	-1	V
		$I_C$ = -500 mA; $I_B$ = -50 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.01; $T_{amb}$ = 25 °C	-	-	-1.2	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = -10 V; $I_{C}$ = -50 mA; f = 100 MHz; $T_{amb}$ = 25 °C	100	-	-	MHz



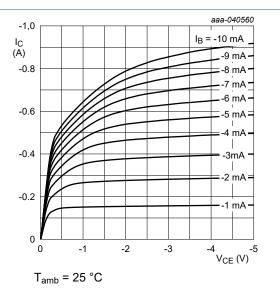


Fig. 5. Collector current as a function of collectoremitter voltage; typical values

#### 80 V, 1 A PNP medium power transistor

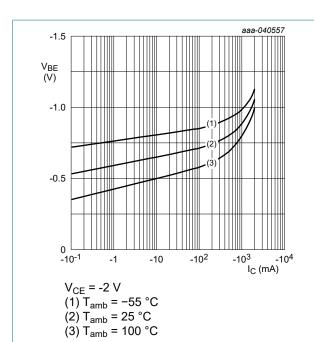
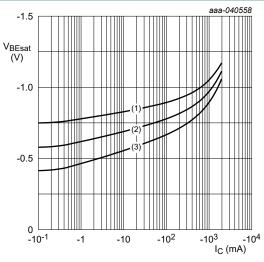
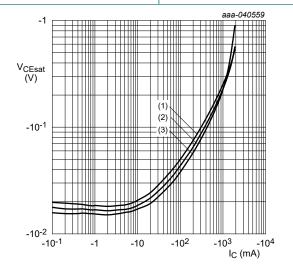


Fig. 6. Base-emitter voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 10$ (1)  $T_{amb} = -55 \,^{\circ}C$ (2)  $T_{amb} = 25 \,^{\circ}C$ (3)  $T_{amb} = 100 \,^{\circ}C$ 

Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values



 $I_C/I_B = 10$ 

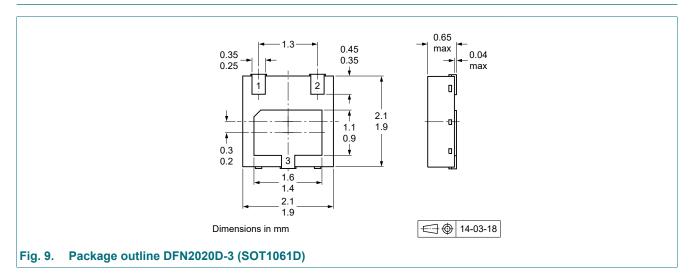
 $(1) T_{amb} = 100 °C$ 

(2)  $T_{amb} = 25 \text{ °C}$ (3)  $T_{amb} = -55 \text{ °C}$ 

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

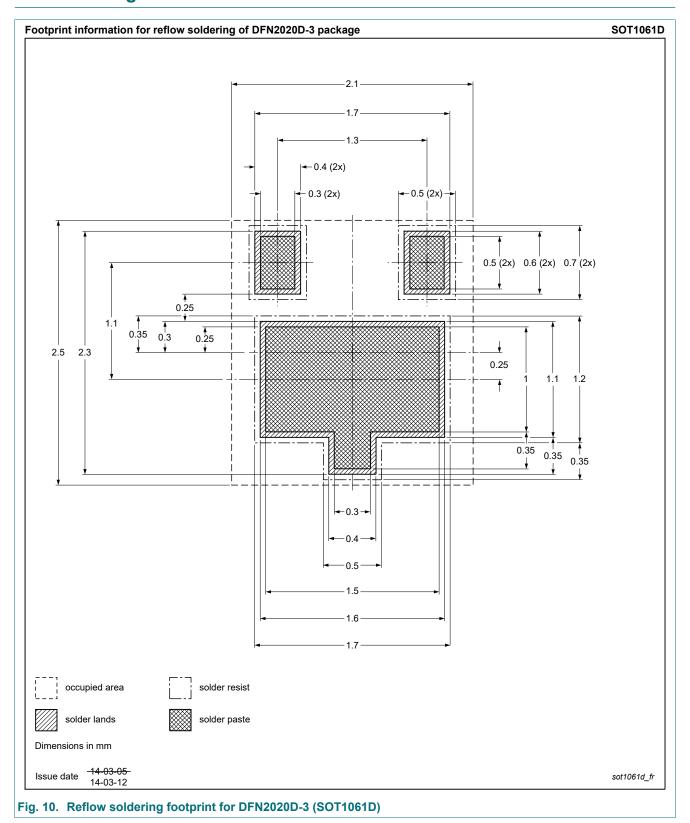
## 80 V, 1 A PNP medium power transistor

# 11. Package outline



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## 12. Soldering



## 80 V, 1 A PNP medium power transistor

# 13. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BSR33PAS v.1	20240909	Product data sheet	-	-

## 80 V, 1 A PNP medium power transistor

## 14. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## 80 V, 1 A PNP medium power transistor

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